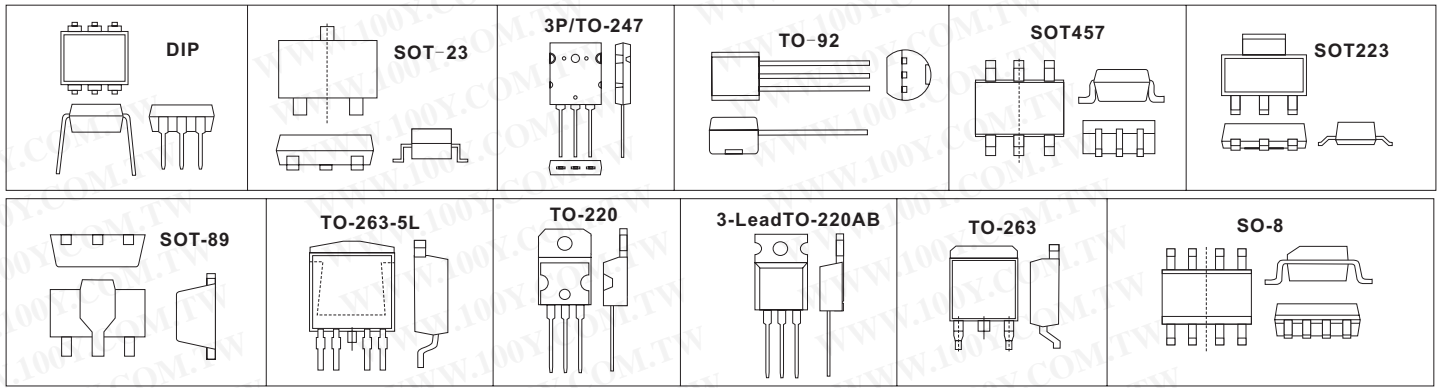


Semiconductors – Discretes

Other Series Power MOSFET

Detailed product specifications are available on: us.100y.com.tw



Part No.	Product No.	Manufacturer	Description	Pin/Package	Id(max.) A	Rds(on)(max.) Ω	Pd(max.) W	Vdss(max.) V	N/P Ch.	
39636	74OL6000	Fairchild	Applications and operation of optologic TM	DIP	60mA			15V	N	
34155	AO3400		N-Channel Enhancement Mode Field Effect Transistor	SOT-23	5.8A			30V	N	
39577	APT5020BVFR	APT	N-Ch. Enhancement power MOSFET	TO-247	26	0.2	300W	500V	N	
16294	APT5020BVR	APT	N-Ch. Enhancement power MOSFET	3P/TO-247	26A	0.2Ω	300W	500V	N	
22498	BS107		Small Signal MOSFET 250 mAmps, 200 Volts	3P/TO-92	250-500mA	14Ω	350mW	200Vdc	TO-92	
22499	BS107T	PHILIPS	N-channel enhancement mode vertical D-MOS transistor	3P/TO-92	150mA	28Ω	830mW	200V	TO-92	
41857	BS170	ON-Semi.	Small Signal MOSFET 500 mAmps 60 Volts	TO-92	0.5A	5000mΩ	0.35W	60V	N CHANNEL	
41858	BS170RLRM	ON-Semi.	Small Signal MOSFET 500 mAmps, 60 Volts	TO-92	0.5A	5000mΩ	0.35W	60V	N	
29470	BSH103	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	0.85A	0.5Ω	0.5W	30V	N-ch.	
29471	BSH105	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	1.05A	250mΩ		20V	N-ch.	
29473	BSH108	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	1.9A		0.83W	30V	N-ch.	
29451	BSH201	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	-0.3A	3.75Ω		-60V	P-Ch.	
29452	BSH202	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	-0.52A	1.35Ω		-30V	P-Ch.	
29453	BSH203	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	-0.47A	1.1Ω		-30 V	P-Ch.	
29454	BSH205	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	-0.75A	0.5Ω		-12V	P-Ch.	
29455	BSH207	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT457	-1.52A	230mΩ		-12V	P-Ch.	
29474	BSN20	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	0.173A		0.83W	50V	N-ch.	
29480	BSP030	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT223	10A		8.3W	30V	N-ch.	
29483	BSP100	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT223	6A		8.3W	30V	N-ch.	
45724	BSP126	PHILIPS								
29456	BSP220	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT223	-0.225A	12Ω	1.5W	-200V	P-Ch.	
29457	BSP225	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT223	-0.225A	15Ω	1.5W	-250V	P-Ch.	
29458	BSP230	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT223	-0.21A	17Ω	1.5W	-300V	P-Ch.	
29459	BSP250	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT223	-3A	0.25Ω	5W	-30V	P-Ch.	
29461	BSP254	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	TO-92	-0.2A	15Ω	1W	-250V	P-Ch.	
29460	BSP254A	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	TO-92	-0.2A	15Ω	1W	-250V	P-Ch.	
29462	BSP304	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	TO-92	-0.17A	17Ω	1W	-300V	P-Ch.	
29463	BSP304A	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	TO-92	-0.17A	17Ω	1W	-300V	P-Ch.	
41859	BSP52T1G	ON-Semi.	Small Signal Darlington	SOT-223	1A			80V	NPN	
44485	BSS138	SIEMENS	SIPMOS Small-Signal Transistor	SOT-23	0.22A	3.5Ω	0.36W	50V	N	
41860	BSS138LT1	ON-Semi.	Power MOSFET 200 mAmps, 50 Volts	SOT-23	0.2A	3500mΩ	0.225W	50V	N-Channel	
29464	BSS192	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT89	-0.2A	12Ω	1W	-240V	P-ch.	
29465	BSS84	PHILIPS	PHILIPS_ N-channel enhancement mode MOS transistor	SOT23	-0.13A	10Ω	250mW	-50V	P-Ch.	
29170	BUK111-50GL	PHILIPS	Logic level TOPFET	TO-263-5L	12A	90m Ohm	52W	50V		
32208	BUZ11	ST(SGS)	N-Channel Power MOSFET	3P/TO-220	33A	0.04Ω	120W	50V	N	
3926	BUZ11	SIEMENS	N-Channel Power MOSFET	3P/TO-220	36A	0.04Ω	120W	50V	N	
28946	BUZ21	Infineon	N-channel enhancement mode MOS transistor	TO-220AB	21A	0.085Ω	75W	100V	N-Ch.	
16851	BUZ61A	Infineon	SIEMENS_ N-channel enhancement mode MOS transistor	TO-220AB	11A	0.5Ω	150W	400V	N-Ch.	
21342	CEB6060L	CET	N-Channel Enhancement Mode Field Effect Transistor	3P[TO-263(DD-PAK)]	48A		10Vgs/20mΩ 5Vgs/25mΩ	100W	60V	N
26475	CEM9435A	CET	Dual N-channel enhancement mode field effect transistor	8P/SOIC	±3.3A		10VDS/50mΩ 4.5Vds/90mΩ	2W	-30V	P
14402	CEM9945	CET	Dual N-channel enhancement mode field effect transistor	8P/SOIC	±3.3A		10Vbs/0.1Ω 4.5Vbs/0.2Ω	2W	60V	N
32934	D1001UK	SEME LAB	Gold metallised multi-purpose silicon dmos rf fet 20W - 28V - 175MHz SINGLE ENDED		5A			50W	70V	

